

10th International Conference on Hot Wire (Cat) & Initiated Chemical Vapor Deposition (HWCVD10)

Conference Program

Monday September 3, 2018

09:00-09:10 **Welcome Remarks**

Plenary	Chair : K.K.S. Lau Drexel University, USA
09:10-09:50 Mo-PL-1 Invited	Current status of Cat-CVD technology - history of research and current status of industrial implementation - H. Matsumura Japan Advanced Institute of Science and Technology (JAIST), Japan
Keynote I	Chair : K.K.S. Lau Drexel University, USA
09:50-10:30 Mo-KE-1 Invited	Hot-wire CVD developments and applications L. Schäfer Fraunhofer Institute for Surface Engineering and Thin Films IST, Germany
10:30-10:50	Coffee break
Special Tutorial	Chair : H. Horibe Osaka City University, Japan
10:50-11:30 Mo-ST-1 Invited	Detection of molecular radical species in catalytic and initiated chemical vapor deposition processes H. Umemoto Shizuoka University, Osaka City University, Japan
11:30-13:00	Lunch
Fundamentals	Chair : K. Ohdaira Japan Advanced Institute of Science and Technology (JAIST), Japan
13:00-13:40 Mo-O1-1 Invited	Modeling of chemical vapor deposition reactions and processes M. Kawase Kyoto University, Japan
13:40-14:00 Mo-O1-2	No shown A computational model for n-butyl acrylate film deposition in initiated chemical vapor deposition process S. Ates*, O. Ebil *Izmir Institute of Technology, Turkey
14:00-14:20 Mo-O1-3	Decomposition of hexamethyldisilazane on a hot tungsten filament and gas-phase reactions in a hot-wire chemical vapor deposition reactor E. Ampong, Y. Shi* *University of Calgary, Canada
14:20-14:40 Mo-O1-4	Surface reactions on the metal catalysts with ethane and four-membered-ring organosilicon molecules Y. Shi University of Calgary, Canada
14:40-15:00	Coffee break

Processes I	Chair : A.Y. Kovalgin University of Twente, Netherlands
15:00-15:40 Mo-O2-1 Invited	The highs and lows of iCVD K.K.S. Lau Drexel University, USA
15:40-16:00 Mo-O2-2	Deposition of polymer films onto moving substrates C. Cheng*, M. Gupta *University of Southern California, USA
16:00-16:20 Mo-O2-3	Withdrawn Polymeric thin film fabrication via initiated chemical vapor deposition for protection of optical surfaces M. Ozpirin*, O. Ebil *Izmir Institute of Technology, Turkey
Applications I	Chair : Y. Katamune Kyushu Institute of Technology, Japan
16:20-17:00 Mo-O3-1 Invited	Various applications of hot-wire chemical vapor deposition to solar-cell fabrication technologies A. Masuda National Institute of Advanced Industrial Science and Technology (AIST), Japan
17:30-19:30	Social

Tuesday September 4, 2018

Processes II	Chair : Y. Shi University of Calgary, Canada
09:00-09:40 Tu-O1-1 Invited	Hotwire-assisted atomic layer deposition: principles and examples A.Y. Kovalgin University of Twente, Netherlands
09:40-10:00 Tu-O1-2	Selective coating of nanostructures in normal pressure and temperature based on surface curvature V.A. Lovikka*, M. Leskelä *University of Helsinki, Finland
10:00-10:20 Tu-O1-3	A simplest Cat-CVD apparatus without direct substrate heating system H. Matsumura*, K. Koyama, K. Ogawa, S. Terashima, T. Konishi, T. Baba, Y. Takeuchi, K. Ohdaira *Japan Advanced Institute of Science and Technology (JAIST), Japan
10:20-10:40 Tu-O1-4	How hot is the wire: optical, electrical and combined methods of filament temperature determination A.J. Onnink*, A.Y. Kovalgin, J. Schmitz *University of Twente, Netherlands
10:40-11:00	Coffee break
Processes III	Chair : S. Ohmagari National Institute of Advanced Industrial Science and Technology (AIST), Japan
11:00-11:40 Tu-O2-1 Invited	Leading role of HWCVD for diamond and related thin films and coating materials: from advanced instrumentation, industrial applications to future devices R.D. Vispute Blue Wave Semiconductors, Inc., USA

11:40-12:00 Tu-O2-2 Charge effect on diamond nanoparticles generated in gas phase in hot filament chemical vapor deposition.
H.Y. Kim*, B.-K. Song, K.-S. Kim, N.-M. Hwang
*Seoul National University, Korea

Tu-O2-3 Withdrawn
~~Hot wire chemical vapour deposition aided growth of nano graphene at low substrate temperature~~
~~S. Ramakrishna, R.O. Dusane*~~
~~*Indian Institute of Technology Bombay, India~~

12:00-13:40 Lunch

Materials I Chair : M. Sato

13:40-14:20 Tu-O3-1 Transferfree 4-inch-scale high-quality monolayer graphene synthesis on Ti-buffered substrates
Invited
B.-J. Park, J.-S. Choi, H. Ha, H.Y. Kim, K.-S. Kim, Z. Lee, G. Park, H.-T. Jung, J.-H. Eom, S.-G. Yoon*
*Chungnam National University, Korea

14:20-14:40 Tu-O3-2 Low-temperature formation of nanographene on Cu substrate using pentacene
A. Heya*, N. Matsuo
*University of Hyogo, Japan

14:40-15:00 Coffee break

Materials II Chair : A. Heya

15:00-15:20 Tu-O4-1 Growth of graphene on non-catalytic substrate by the vapor pressure of catalytic metal
J. Baek*, J. Kim, J. Kim, T. Suh, B. Shin, S. Jeon
*Korea Advanced Institute of Science and Technology (KAIST), Korea

15:20-15:40 Tu-O4-2 High quality and monolayer graphene synthesized directly at 150 °C via chemical vapor deposition without transfer process
B.-J. Park, S.-G. Yoon*
*Chungnam National University, Korea

15:40-16:00 Tu-O4-3 Synthesis of vertically aligned carbon nanoflakes by hot wire chemical vapor deposition: influence of process pressure and substrate temperature
M. Singh, H.S. Jha, P. Agarwal*
*Indian Institute of Technology Guwahati, India

16:00-16:20 Coffee break

16:20-18:00 **Poster session**

Wednesday September 5, 2018

Materials III Chair : K. Yasui

09:40-10:20 We-O1-1 Transparent passivated contact and phosphorous catalytic-doping for crystalline silicon solar cells
Invited
M. Pomaska*, Y. Liu, F. Komoll, A. Lambertz, W. Duan, H. Li, D. Qiu, M. Köhler, F. Finger, U. Rau, K. Ding
*Forschungszentrum Juelich, Germaney

We-O1-2	Withdrawn Effect of filament temperature on optoelectronic properties of hydrogenated microcrystalline silicon thin films deposited by HWCVD S. Shende, N. Wadibhasme, S.V. Ghaisas, R.O. Dusane Indian Institute of Technology Bombay, India
We-O1-3	Withdrawn Hot wire CVD driven silicon nanowire growth below eutectic temperature using Sn nanotemplate N. Meshram*, A. Kumbhar, R.O. Dusane *Indian Institute of Technology Bombay, India
10:20-10:40	We-O1-4 Silicon carbide charged nanoparticles generated during a hot filament chemical vapor deposition D.-Y. Kim*, D. Kim, J.H. Kwon, N.-M. Hwang *Seoul National University, Korea
10:40-11:00	Coffee break
Materials IV	Chair : S.-G. Yoon Chungnam National University, Korea
11:00-11:20	We-O2-1 Large reduction of threading dislocation in diamond by hot-filament CVD S. Ohmagari, H. Yamada, S. Tanaka, N. Tsubouchi, H. Umezawa, A. Chayahara, Y. Mokuno National Institute of Advanced Industrial Science and Technology (AIST), Japan
11:20-11:40	We-O2-2 Surface morphology of homoepitaxial diamond grown by hot-filament CVD using organic phosphorus solutions. Y. Katamune*, D. Arikawa, D. Mori, A. Izumi *Kyushu Institute of Technology, Japan
11:40-12:00	We-O2-3 Synthesis and characterization of diamond capsules for direct-drive inertial confinement fusion H. Kato*, H. Yamada, S. Ohmagari, A. Chayahara, Y. Mokuno, Y. Fukuyama, N. Fujiwara, K. Miyanishi, Y. Hironaka, K. Shigemori *Osaka University, Japan
12:00-12:20	We-O2-4 Nitrogen doping of ZnO films using Ir hot-wire in catalytic reaction-assisted CVD Y. Adachi, S. Ono, A. Kato, A.M. Hashim, K. Yasui* *Nagaoka University of Technology, Japan
12:20-14:00	Lunch
Applications II	Chair : M. Pomaska Forschungszentrum Juelich, Germaney
14:00-14:20	We-O3-1 Conformal deposition of thin film silicon solar cells with ultrathin photoabsorbers on nanostructured surfaces R.E.I. Schropp*, L.W. Veldhuizen, Y. Kuang * University of the Western Cape, South Africa
We-O3-2	Withdrawn Development of silicon based thin film solar cells using HWCVD on low cost mild steel substrates N.A. Wadibhasme, P.K. Bijalwan, A. Chikhalkar, M. Agarwal, M. Dutta, R.O. Dusane* *Indian Institute of Technology Bombay, India

Applications III Chair : M. Pomaska

- 14:20-14:40 We-O4-1 Forschungszentrum Juelich, Germaney
Conversion of conduction type of Cat-CVD p-type a-Si by ion implantation
H.T.C. Tu*, K. Koyama, N. Yamaguchi, H. Suzuki, K. Ohdaira, H. Matsumura
*Japan Advanced Institute of Science and Technology (JAIST), Japan

- 14:40-15:00 We-O4-2 **Withdrawn**

~~A novel processing method to pattern hot wire chemical deposited a-Si:H for application in pressure sensing device~~
V. Pandey*, M.P. Gururajan, R.O. Dusane
*Indian Institute of Technology Bombay, Ujjain Engineering College, India

- 15:00-15:20 We-O4-3 Chemical vapor deposition of ultra-thin functional polymer layers for the development of advanced biosensors & microfluidic devices
C. Neikirk*, Y. Melnik, P. Narwankar
*Applied Materials, USA

- 16:30- Field trip & Banquet

Thursday September 6, 2018**Keynote II** Chair : R.E.I. Schropp

- 09:00-09:40 Th-KE-1 University of the Western Cape, South Africa
HW/CAT-CVD for high performance crystalline silicon heterojunction solar cells
Invited Q. Wang
Jinko Solar, China

Applications IV Chair : R.E.I. Schropp

- University of the Western Cape, South Africa
Th-O1-1 **Withdrawn**
~~Optimization of boron doped hydrogenated amorphous Si layers prepared by hot-wire CVD technique for n-type crystalline Si hetero-junction solar cells~~
A. Mandal, N. Wadibhasme, A. Kumbhar, S.V. Ghaisas, R.O. Dusane*
*Indian Institute of Technology Bombay, India
- 10:00-10:20 Th-O1-2 Annealing behavior of Cat-CVD p-type a-Si for c-Si surface passivation and its superiority over PECVD counterparts
H.T.C. Tu*, K. Ohdaira, H. Matsumura
*Japan Advanced Institute of Science and Technology (JAIST), Japan

- 10:20-10:40 Coffee break

Applications V Chair : K. Shimizu

- Nihon University, Japan
10:40-11:00 Th-O2-1 **Excellent passivation quality of MPAT crystalline silicon textures for solar cells by using proper chemical cleaning and Cat-CVD SiN_x/a-Si stacked layers**
C.T. Nguyen*, K. Ohdaira, H. Matsumura
*Japan Advanced Institute of Science and Technology (JAIST), Japan
- 11:00-11:20 Th-O2-2 **Improvement in the passivation quality of Cat-CVD SiN_x films on crystalline Si at room temperature**
J. Miyaura, K. Ohdaira*
*Japan Advanced Institute of Science and Technology (JAIST), Japan

11:20-11:40 Th-O2-3 **Tunnel oxide passivated contact for crystalline silicon solar cells using hot-wire chemical vapor deposition**

S. Li*, M. Pomaska, J. Hoß, W. Wang, J. Lossen, F. Pennartz, M. Nuys, F. Finger, U. Rau, K. Ding

*Forschungszentrum Jülich, Germaney

11:40-12:00 **Closing Remarks**

10th International Conference on Hot Wire (Cat) & Initiated Chemical Vapor Deposition (HWCVD10)

Poster session

Tuesday September 4, 2018 16:20-18:00

- Tu-P-01 **Oxygen additive effects on decomposition rate of poly(vinyl phenol)-based polymers using hydrogen radicals produced by a tungsten hot-wire catalyst**
M. Yamamoto*, S. Nagaoka, K. Ohdaira, H. Umemoto, H. Horibe
*National Institute of Technology, Kagawa College, Japan
- Tu-P-02 **Removal of carbon contamination on easily-oxidizable-metal coated mirrors for synchrotron radiation beamline using atomic hydrogen**
M. Niibe*, T. Harada, A. Heya, T. Watanabe, N. Matsuo
*University of Hyogo, Japan
- Tu-P-03 **Role of chamber pressure on crystallinity and composition of silicon films using silane and methane as precursors in HWCVD technique**
R. Madaka, J. Kumari, V. Kanneboina, H.S. Jha, P. Agarwal*
*Indian Institute of Technology Guwahati, India
- Tu-P-04 **In situ cleaning of silicon substrate by atomic hydrogen and argon and its application for solar cells**
Y. Someya*, K. Shimizu
*Nihon University, Japan
- Tu-P-05 **Passivation of crystalline silicon surfaces with a few μm -sized pyramids by Cat-CVD silicon nitride films**
J. Liu, Y. Wen*, N. Ooyagi, Y. Yamamoto, K. Ohdaira
*Japan Advanced Institute of Science and Technology (JAIST), Japan
- Tu-P-06 **Influence of ITO sputtering on the performance of silicon heterojunction solar cells with Cat-CVD amorphous silicon films**
T. Konishi, K. Ohdaira*
*Japan Advanced Institute of Science and Technology (JAIST), Japan
- Tu-P-07 **Large area HWCVD processes for Si heterojunction solar cells**
O. Astakhov, M. Justianto, T. Harig, M. Höfer, V. Sittinger, K. Ding*
*Forschungszentrum Jülich GmbH, Germaney
- Tu-P-08 **HWCVD for silicon photonics: a new industrial application**
A. Tarazona*, S.Z. Oo, T.D. Bucio, R. Petra, A.Z. Khokhar, V. Mittal, F.Y. Gardes, G.T. Reed, H.M.H. Chong
*University of Southampton, UK
- Tu-P-09 **Growth of highly nanocrystalline cubic silicon carbide (3C-SiC) thin films prepared by hot wire chemical vapor deposition technique**
H.S. Jha*, P. Agarwal
*Indian Institute of Technology Guwahati, India, Gifu University, Japan
- Tu-P-10 **Substrate temperature dependence of SiO_2 layer formed on Si(100) by $\text{H}_2\text{O}/\text{H}_2$ decomposed species**
S. Tahara*, K. Fukushima, Y. Katamune, A. Izumi
*Kyushu Institute of Technology, Japan

- Tu-P-11 **Evaluation of composition and electrical characteristics of SiOCN thin films deposited by HWCVD**
M. Matsumoto*, H. Tsutsui, Y. Katamune, A. Izumi
*Kyushu Institute of Technology, Japan
- Tu-P-12 **Evaluation of corrosion resistance of SiOCN film by HWCVD method**
K. Fukushima*, S. Tahara, Y. Katamune, A. Izumi
*Kyushu Institute of Technology, Japan
- Tu-P-13 **Cu diffusion properties of SiCN films deposited by hot-wire chemical vapor deposition**
H. Tsutsui*, S. Hayashida, Y. Katamune, A. Izumi
*Kyushu Institute of Technology, Japan
- Tu-P-14 **Preparation of ZrO_xN_y film at low temperatures by reactive sputtering assisted by hot-wire**
M. Sato*, H. Kitada, M.B. Takeyama
*Kitami Institute of Technology, Japan
- Tu-P-15 **Hot-wire hydrogenation for In-Sn-Zn-O and improvement of the TFT reliability**
T. Yanagisawa*, Y. Someya, K. Shimizu
*Nihon University, Japan
- Tu-P-16 **Investigation of diamond growth on SiCN films deposited by hot wire CVD**
F. Morishita*, Y. Katamune, A. Izumi
*Kyushu Institute of Technology, Japan
- Tu-P-17 **Micro-sized diamond growth using organic phosphorus solution by hot filament chemical vapor deposition**
D. Arikawa*, D. Mori, Y. Katamune, A. Izumi
*Kyushu Institute of Technology, Japan
- Tu-P-18 **Structural evaluation of polycrystalline diamond films grown by hot filament CVD using organic phosphorus solutions**
D. Mori*, D. Arikawa, Y. Katamune, A. Izumi
*Kyushu Institute of Technology, Japan
- Tu-P-19 **Thermally stable diamond resistors fabricated by hot-filament CVD accompanying metal masks**
S. Suzuki*, S. Ohmagari, H. Kawashima, H. Umezawa
*National Institute of Advanced Industrial Science and Technology (AIST), Japan
- Tu-P-20 **Change in optical transmittance of carbon nanowall by oxygen plasma treatment**
K. Tanabe*, H. Yamamoto, Y. Ieda, S. Hanada, S. Yamada, T. Itoh, S. Nonomura
*Gifu University, Japan
- Tu-P-21 **Investigation for large area deposition of carbon nanowall by hot-wire chemical vapor deposition**
T. Itoh*, H. Sobue, K. Hayashi, S. Hanada, H. Yamamoto, S. Yamada, S. Nonomura
*Gifu University, Japan
- Tu-P-22 **Semiconducting properties of nitrogen doped-graphene by in-situ synthesis at 150 °C**
Y.-Han*, B.-J. Park, M.-W. Nam, S.-G. Yoon
* Chungnam National University, Korea